

1/1: GS8554-EX.11  
2/2: GS8554-EX.22

Pulse input isolated barriers, provide isolated power supply(24V) for field instruments. The pulse signal generated in the hazardous-area device is transmitted to the safe-area through the isolated barrier to output. The input adopts hysteresis comparison circuit which has high anti-interference performance. The product needs an independent power supply and galvanic isolation among power supply, input and output.

## Specification

**Supply Voltage:** 20~35V DC

**Current Consumption:** (Supply voltage: 24V; output: 12V voltage pulse)  
 $\leq 160\text{mA}$ (GS8554-EX.22, 24V distribution voltage)  
 $\leq 90\text{mA}$ (GS8554-EX.11, 24V distribution voltage)

### Safe-area Output:

Transistor Output: Supply voltage  $V_{CC} \leq 40\text{V}$ , Rated current  $\leq 40\text{mA}$

Transistor Collector Output:

$V_H = V_{CC}$ ;  $V_L \leq 2.5\text{V}$ (On-state current=10mA,  $V_{CC}=24\text{V}$ )

Load Resistance:  $2\text{k}\Omega \leq R_L \leq 20\text{k}\Omega$

Transistor Emitter Output:

$V_H \geq V_{CC} - 2.5\text{V}$ ;  $V_L \leq 0.5\text{V}$ (On-state current=10mA,  $V_{CC}=24\text{V}$ )

Load Resistance:  $2\text{k}\Omega \leq R_L \leq 20\text{k}\Omega$

### Voltage pulse Output:

24V Range PLC/DCS: High Voltage  $16\text{V} \leq V_H \leq 24\text{V}$

12V Range PLC/DCS: High Voltage  $9\text{V} \leq V_H \leq 12\text{V}$

Low Voltage:  $V_L \leq 0.5\text{V}$

Load Resistance:  $R_L \geq 1\text{k}\Omega$ , Rated current  $\leq 10\text{mA}$

### Hazardous-area Input:

Voltage pulse Input: High voltage  $V_H \geq 4\text{V}$ ; Low voltage  $V_L \leq 1\text{V}$

Frequency at voltage pulse output  $\leq 50\text{kHz}$

Frequency at transistor output  $\leq 20\text{kHz}$

Transistor Input: NPN/PNP

Frequency at voltage pulse output  $\leq 20\text{kHz}$

Frequency at transistor output  $\leq 10\text{kHz}$

(Input signal  $V_H \leq 12\text{V}$ , Duty ratio  $\geq 30\%$ )

The input signal type can be set by the DIP switches:

Sta.	Input 1		Input 2	
	K4	K3	K2	K1
Voltage pulse Input	OFF	OFF	OFF	OFF
Emitter (PNP) Input	OFF	ON	OFF	ON
Collector (NPN) Input	ON	OFF	ON	OFF

Distribution power: Open-voltage:  $\leq 26\text{V}$ ; Rated voltage:  $\geq 16\text{V}$  at 20mA

Note: a) K1 and K2 cannot be ON at the same time;

b) K3 and K4 cannot be ON at the same time.

**Power Supply Protection:** Power supply reverse protection

**EMC:** According to IEC 61326-1(GB/T 18268)

**Ambient Temperature:**  $-20^\circ\text{C} \sim +60^\circ\text{C}$

**Dielectric Strength:**

Between non-intrinsically safe part and intrinsically safe part  $\geq 2500\text{V AC}$

Between power supply part and output part  $\geq 1500\text{V AC}$

**Structure:** GS8500 range structure customized by Phoenix Contact.

**Weight:** Approx. 150g

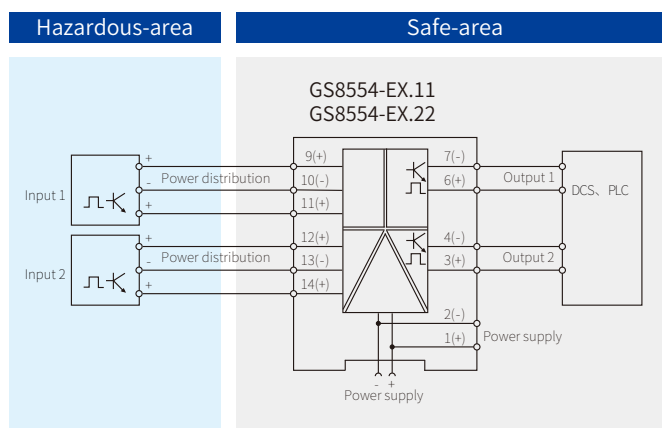
**Suitable Location:** Mounting in safe area, and connected to the IS apparatus in hazardous area up to zone0 IIC and zone20 IIIC.

**Suitable Field Apparatus:** 2-wire or 3-wire pulse signal source



Dimensions: 118.9mm × 106.0mm × 17.5mm

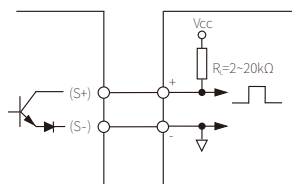
## Connection



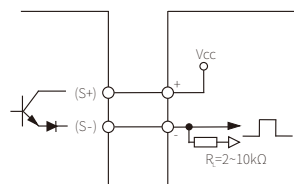
Note: a) GS8554-EX.11 only contains input1, output1;

b) Bus-powered function is optional, if necessary please specified when ordering, and purchase bus power supply accessories in additional.

### Application 1: Transistor Collector Output



### Application 2: Transistor Emitter Output



## Explosion-proof Certificate

**Certifying Authority:** NEPSI(China)

**Ex Marking:** [Ex ia Ga] II C

[Ex iaD]

**Maximum Voltage:**  $U_m = 250\text{V}$

**Intrinsic Safety Parameters(9、10、11; 12、13、14 terminals):**

$U_o = 28\text{V}$ ,  $I_o = 93\text{mA}$ ,  $P_o = 651\text{mW}$

II C:  $C_o = 0.083\mu\text{F}$ ,  $L_o = 4.2\text{mH}$

\*II B:  $C_o = 0.65\mu\text{F}$ ,  $L_o = 12.6\text{mH}$

II A:  $C_o = 2.15\mu\text{F}$ ,  $L_o = 33.6\text{mH}$

\*II B Intrinsic Safety Parameters are also suitable for dust explosion protection[Ex iaD]